



RM008

PA Module for Dual-band GSM900 and DCS1800 Applications

The RM008 is a dual-band Power Amplifier Module (PAM) designed in a compact form factor for Class 4 GSM900 and Class 1 DCS1800 operation.

The PAM consists of two Gallium Arsenide (GaAs) Heterojunction Bipolar Transistor (HBT) power amplifiers and internal components that match the RF input and output ports to 50 ohms, which reduces the number of external components for a dual-band design. Optimized for lithium-ion battery operation, both PAs share common power supply pins to distribute current. The RM008 dual PAM has extremely low standby current, which maximizes handset standby time.

A block diagram of the RM008 is shown below. The Analog Power Control (APC) pins (GSM APC and DCS APC), control output power level. Table 4 of this data sheet shows the complete signal pin assignments and descriptions of the RM008 dual-band Power Amplifier Module.

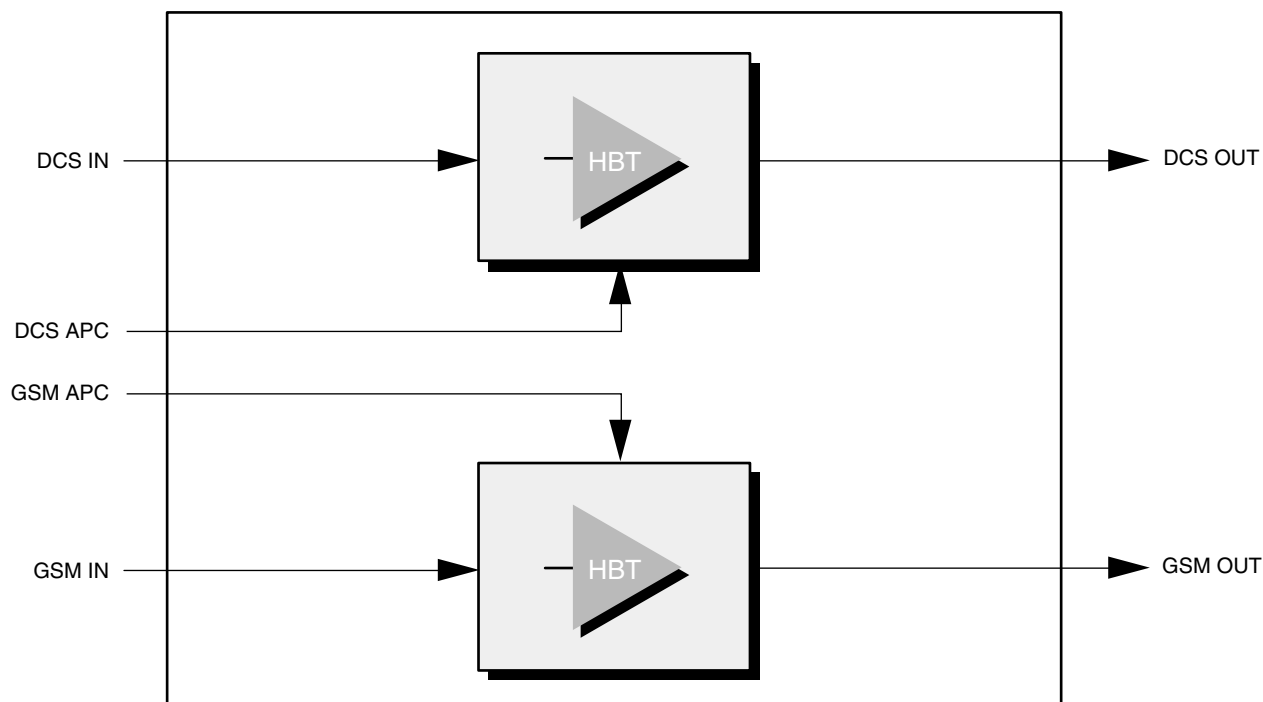
Distinguishing Features

- High efficiency
GSM 50%
DCS 45%
- Input and output matching
50 ohms internal
- Small outline
9.1 mm x 11.61 mm
- Low profile
1.64 mm

Applications

- Class 4 GSM900 and Class 1 DCS1800 dual-band cellular handsets

Functional Block Diagram



Electrical Characteristics

The following tables list the electrical characteristics of the RM008 Power Amplifier. Table 1 depicts the absolute maximum ratings and Table 2 specifies the recommended operating conditions to achieve the performance specifications in Table 3.

Table 1. Absolute Maximum Ratings

Parameter	Minimum	Maximum	Units
Supply Voltage (V_{CC})	—	7	V
Storage Temperature	-55	+125	°C

Table 2. Recommended Operating Conditions

Parameter	Minimum	Typical	Maximum	Units
Supply Voltage (V_{CC})	2.9	3.3	4.6	V
Temperature	-30	—	+85	°C

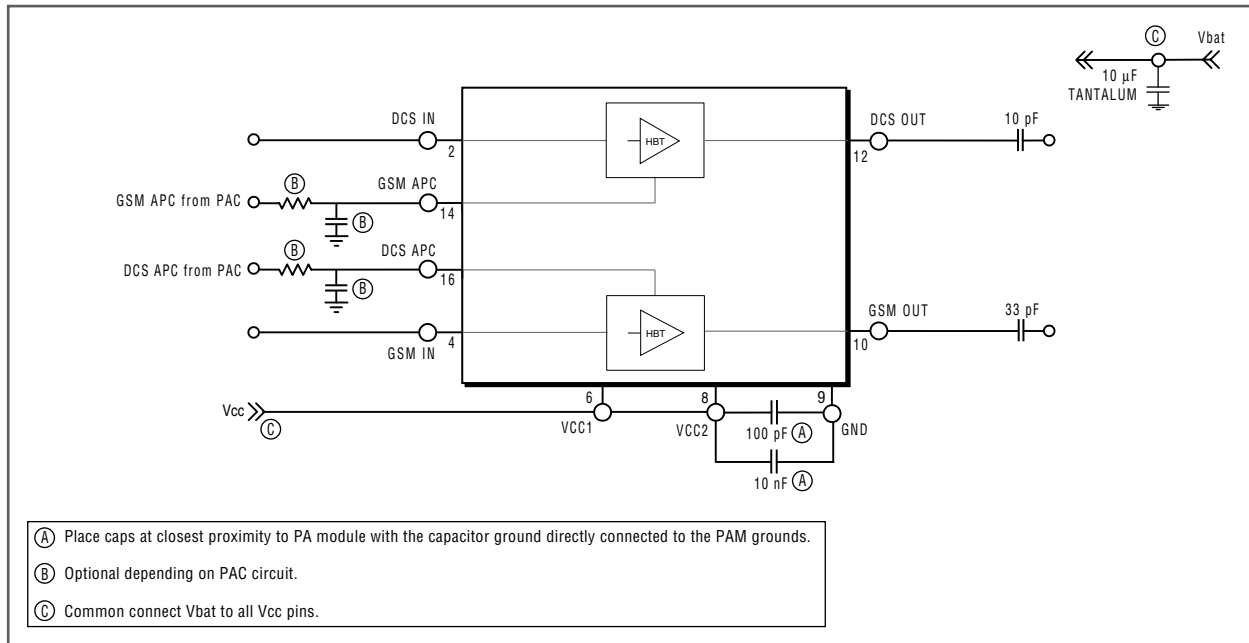
Table 3. Electrical Specifications for Nominal Operating Conditions (1 of 2)

Parameter	Test Conditions	Symbol	Minimum	Typical	Maximum	Units
GSM Mode ($f = 880\text{--}915$ MHz and $P_{IN} = 8$ to 13 dBm)						
Frequency Range	—	f_1	880	—	915	MHz
Input Power	—	P_{INGSM}	8	10	13	dBm
Control Voltage Range	V_{GSMAPC}	V_{APC}	0.2	—	2.5	V
Control Current Into V_{APC}	—	I_{GSMAPC}	—	40	70	mA
Leakage Current	$V_{CC} = 4.6$ V $V_{APC} = 0$ V	$I_{LEAKAGE}$	—	—	25	μ A
Efficiency	$P_{INGSM} = 10$ dBm $P_{OUTGSM} = 34$ dBm	η_{GSM}	—	50	—	%
2nd Harmonic Distortion	$P_{OUTGSM} = 34.5$ dBm	H_{2GSM}	—	—	-5	dBm
3rd–7th Harmonic Distortion	$P_{OUTGSM} = 34.5$ dBm	$H_{3\text{--}H7}$	—	—	-7	dBm
Output Power	$P_{INGSM} = 10$ dBm	P_{OUTGSM}	34.0	34.5	—	dBm
	$P_{INGSM} = 10$ dBm $V_{CC} = 2.9$ V $T_{CASE} = -30$ °C to $+85$ °C	P_{OUTDCS}	32.5	33.0	—	dBm
Input VSWR	All	$VSWR_{(IN)}$	—	1.5:1	2:1	—

Table 3. Electrical Specifications for Nominal Operating Conditions (2 of 2)

Parameter	Test Conditions	Symbol	Minimum	Typical	Maximum	Units
Isolation	$P_{\text{INGSM}} = 10 \text{ dBm}$ $APC = 0.5 \text{ V}$	—	—	—	-30	dBm
Stability Condition VSWR(load) (no spurious oscillation > -35 dBm)	—	—	—	—	8:1 all angles	—
Load Mismatch VSWR(load) (no damage/degradation)	—	—	—	—	10:1 all angles	—
Noise Floor	$P_{\text{INGSM}} = 10 \text{ dBm}$ $BW = 100 \text{ kHz}$ $f_o \pm 20 \text{ MHz offset}$	—	—	—	-85	dBm
Full Power Control Voltage	$P_{\text{OUTGSM}} = 34.5 \text{ dBm}$	—	—	2.0	—	—
DCS Mode (f = 1710–1785 MHz and $P_{\text{IN}} = 6 \text{ to } 11 \text{ dBm}$)						
Frequency Range	—	f2	1710	—	1785	MHz
Input Power	—	P_{INDCS}	6	8.0	11	dBm
Control Voltage Range	V_{DCSAPC}	V_{APC}	0.2	—	2.5	V
Control Current Into V_{APC}	—	I_{DCSAPC}	—	30	70	mA
Leakage Current	$V_{\text{CC}} = 4.6 \text{ V}$ $V_{\text{APC}} = 0 \text{ V}$	I_{LEAKAGE}	—	—	25	μA
Efficiency	$P_{\text{INDCS}} = 8 \text{ dBm}$ $P_{\text{OUTDCS}} = 32 \text{ dBm}$	η_{DCS}	—	45	—	%
2nd Harmonic Distortion	$P_{\text{OUTDCS}} = 32.5 \text{ dBm}$	$H_{2\text{DCS}}$	—	—	-7	dBm
3rd–7th Harmonic Distortion	$P_{\text{OUTDCS}} = 32.5 \text{ dBm}$	H3–H7	—	—	-7	dBm
Output Power	$P_{\text{INDCS}} = 8 \text{ dBm}$	P_{OUTDCS}	32.0	32.5	—	dBm
	$P_{\text{INDCS}} = 8 \text{ dBm}$ $V_{\text{CC}} = 2.9 \text{ V}$ $T_{\text{CASE}} = -30 \text{ }^\circ\text{C to } +85 \text{ }^\circ\text{C}$	P_{OUTDCS}	30.5	31.0	—	dBm
Input VSWR	All	$\text{VSWR}_{(\text{IN})}$	—	1.5:1	2:1	—
Isolation	$P_{\text{INDCS}} = 8 \text{ dBm}$ $APC = 0.5 \text{ V}$	—	—	—	-35	dBm
Stability Condition VSWR (load) no spurious oscillation > -35 dBm)	—	—	—	—	8:1 all angles	—
Load Mismatch VSWR(load) (no damage/degradation)	—	—	—	—	10:1 all angles	—
Noise Floor DCS1800	$P_{\text{INDCS}} = 8 \text{ dBm}$ $BW = 100 \text{ kHz}$ $f_o \pm 20 \text{ MHz offset}$	—	—	—	-77	dBm
Full Power Control Voltage	$P_{\text{OUTDCS}} = 32.5 \text{ dBm}$	—	—	2.0	—	—
NOTE(S): $T_{\text{CASE}} = 25 \text{ }^\circ\text{C}$, $R_L = 50\Omega$, pulsed operation with pulse width = 577 μsec and duty cycle of 1:8, $V_{\text{CC}} = 3.3 \text{ V}$ unless specified otherwise						

Figure 1. Typical RM008 PAM Application

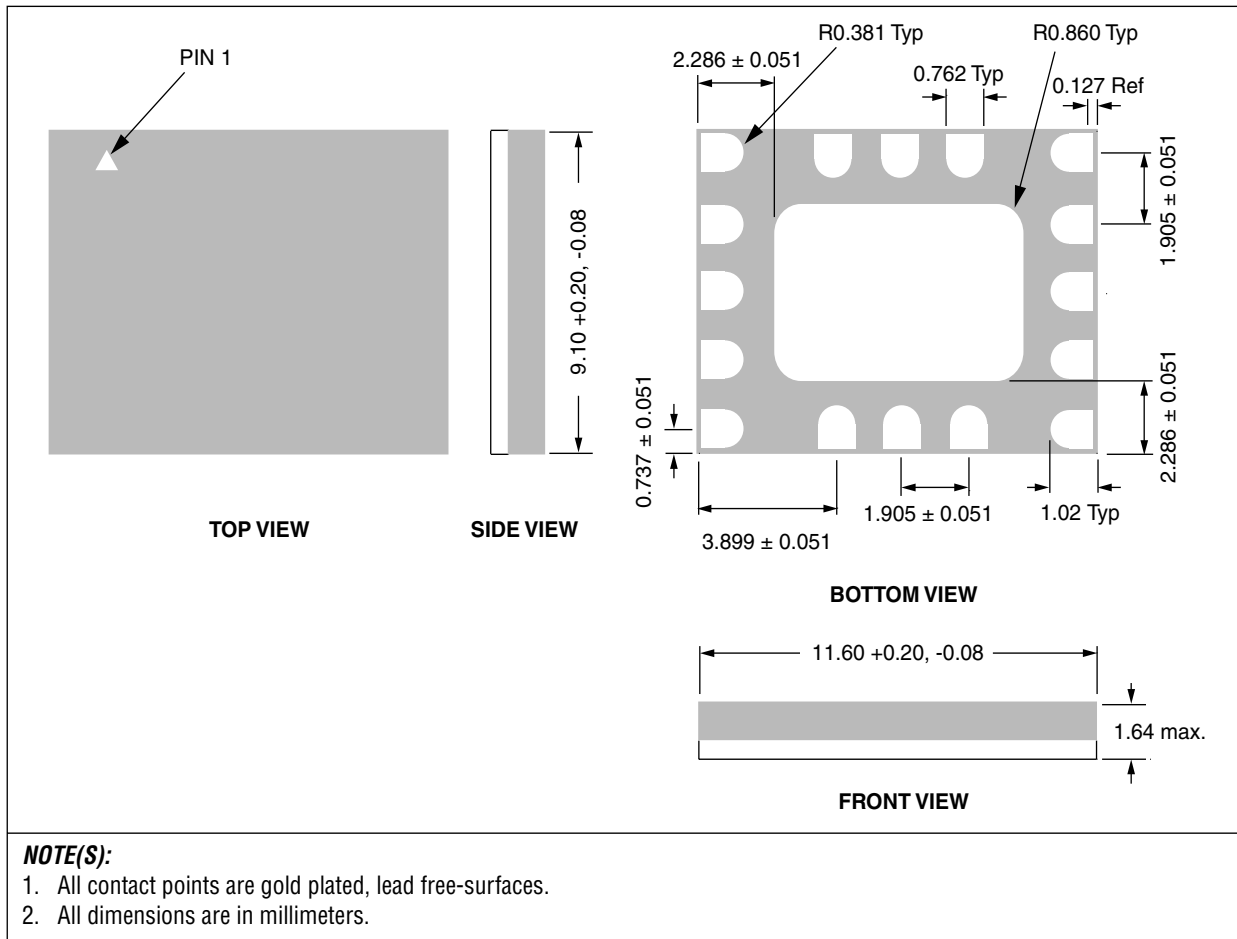


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Package Dimensions and Pin Descriptions

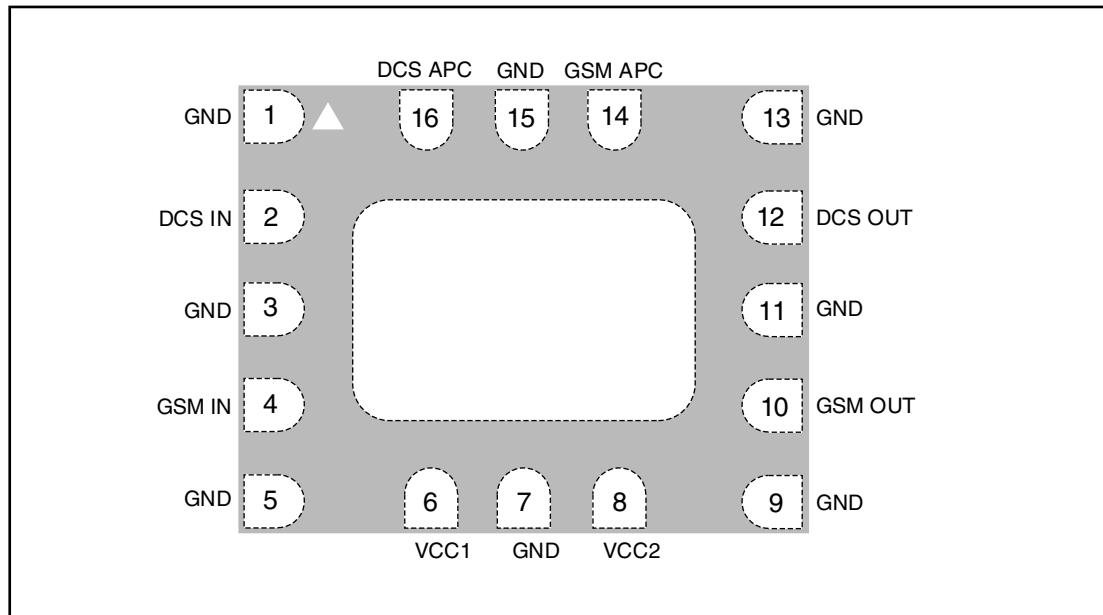
Figure 2 provides the package dimensions for the 16-pin RM008 leadless MCM. Figure 3 shows the device pin configuration and Table 4 lists the pins and signal descriptions.

Figure 2. RM008 Package Dimensions—16-pin PAM (All Views)



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Figure 3. RM008 Pin Configuration–16-Pin Leadless PAM (Top View)



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Table 4. RM008 Pin and Signal Descriptions

PIN	NAME	DESCRIPTION	PIN	NAME	DESCRIPTION
1	GND	Ground	9	GND	Ground
2	DCS IN	RF input to DCS PA	10	GSM OUT	GSM RF output (DC coupled)
3	GND	Ground	11	GND	Ground
4	GSM IN	RF input to GSM PA	12	DCS OUT	DCS RF output (DC coupled)
5	GND	Ground	13	GND	Ground
6	VCC2	Power supply for PA driver stages	14	GSM APC	GSM analog power control
7	GND	Ground	15	GND	Ground
8	VCC2	Power supply for PA output stages	16	DCS APC	DCS analog power control

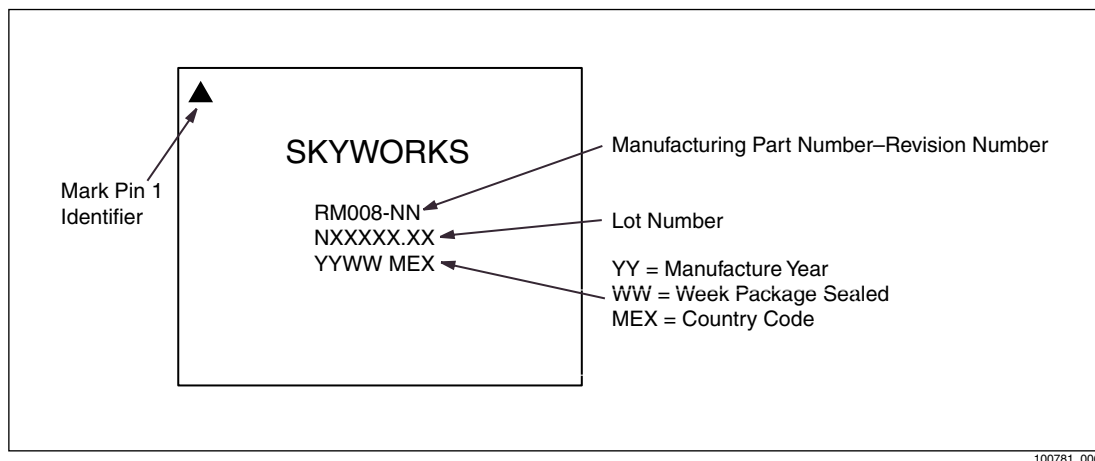
Package and Handling Information

Because of its sensitivity to moisture absorption, this device package is baked and vacuum packed prior to shipment. Instructions on the shipping container label must be followed regarding exposure to moisture after the container seal is broken, otherwise, problems related to moisture absorption may occur when the part is subjected to high temperature during solder assembly.

The RM008 is capable of withstanding an MSL 3/240 °C solder reflow. Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. If the part is attached in a reflow oven, the temperature ramp rate should not exceed 5 °C per second; maximum temperature should not exceed 240 °C. If the part is manually attached, precaution should be taken to insure that the part is not subjected to temperatures exceeding 240 °C for more than 10 seconds.

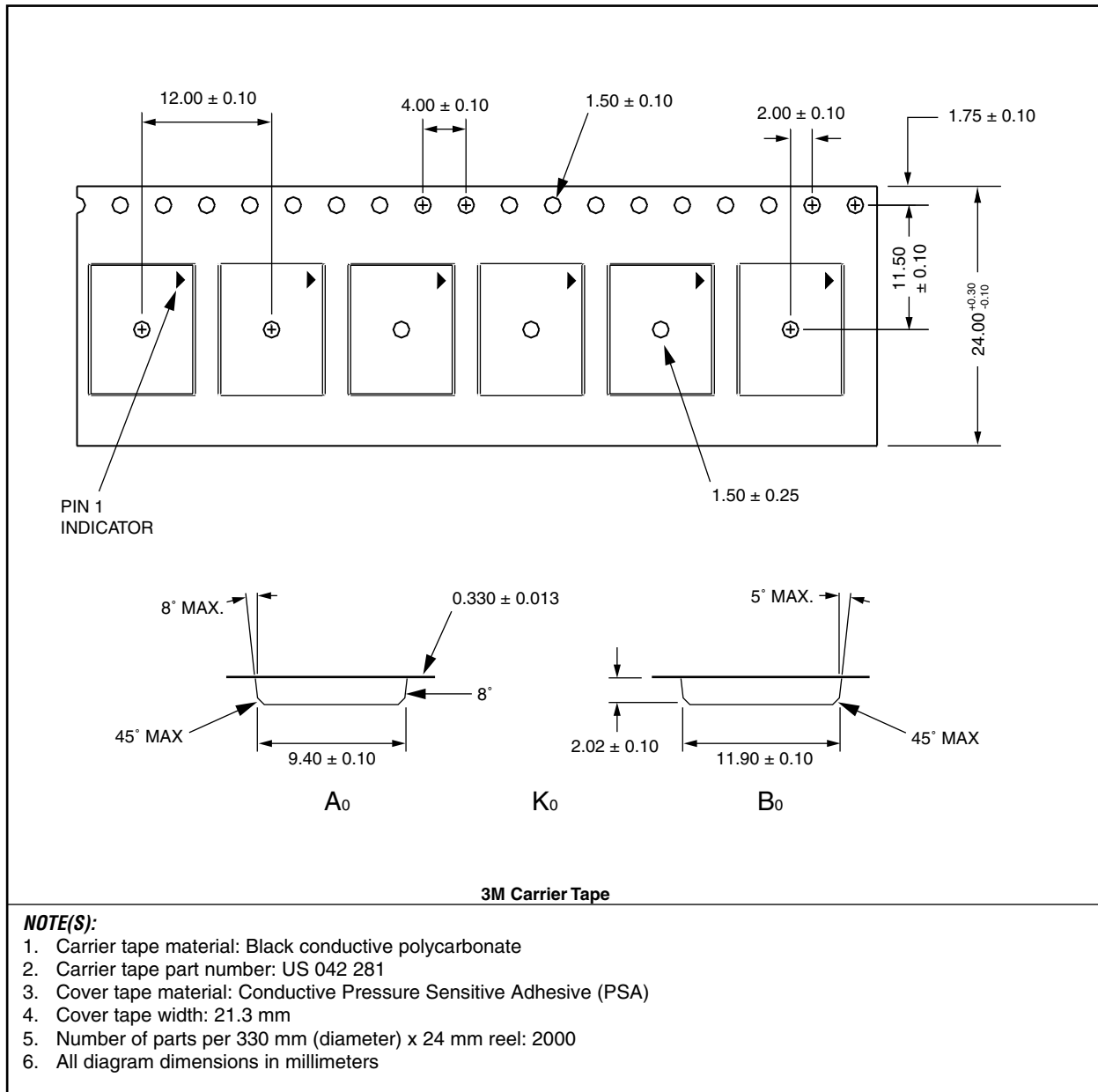
For details on both attachment techniques, precautions, and handling procedures recommended by Skyworks, please refer to *Application Note: PCB Design and SMT Assembly/Rework, Document Number 101752*. Additional information on standard SMT reflow profiles can also be found in the *JEDEC Standard J-STD-020A*.

Figure 4. Typical Case Markings



Production quantities of this product are shipped in the standard tape and reel format illustrated in Figure 5.

Figure 5. RM008 Tape and Reel – 9.1 mm x 11.6 mm

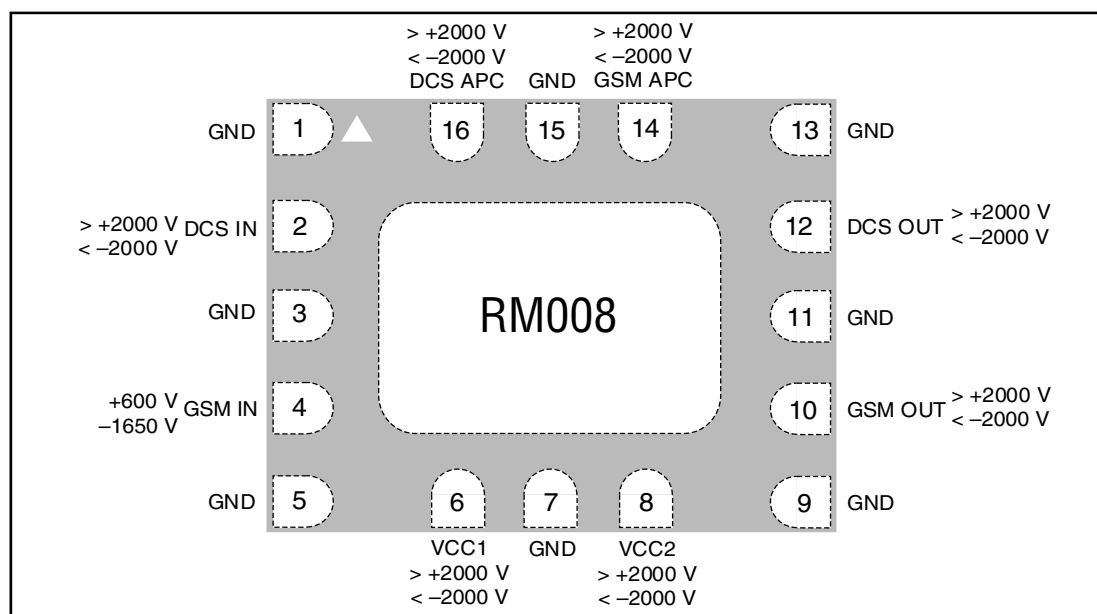


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Electrostatic Discharge Sensitivity

The RM008 is a Class I device. Figure 6 lists the Electrostatic Discharge (ESD) immunity level for each pin of the RM008 product. The numbers in Figure 6 specify the ESD threshold level for each pin where the I-V curve between the pin and ground starts to show degradation. The ESD testing was performed in compliance with MIL-STD-883E Method 3015.7 using the Human Body Model. Since 2000 volts represents the maximum measurement limit of the test equipment used, pins marked > 2000 V pass 2000V ESD stress.

Figure 6. ESD Sensitivity Ares (Top View)



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Various failure criteria can be utilized when performing ESD testing. Many vendors employ relaxed ESD failure standards which fail devices only after “the pin fails the electrical specification limits” or “the pin becomes completely non-functional”. Skyworks employs most stringent criteria, fails devices as soon as the pin begins to show any degradation on a curve tracer.

To avoid ESD damage, both latent and visible, it is very important that the product assembly and test areas follow the Class-1 ESD handling precautions listed in Table 5.

Table 5. Precautions for GaAs ICs with ESD Thresholds Greater Than 200 V But Less Than 2000 V

Personnel Grounding	Facility
Wrist Straps Conductive Smocks, Gloves and Finger Cots Antistatic ID Badges	Relative Humidity Control and Air Ionizers Dissipative Floors (less than 10 ⁹ Ω to GND)
Protective Workstation	Protective Packaging & Transportation
Dissipative Table Tops Protective Test Equipment (Properly Grounded) Grounded Tip Soldering Irons Conductive Solder Suckers Static Sensors	Bags and Pouches (Faraday Shield) Protective Tote Boxes (Conductive Static Shielding) Protective Trays Grounded Carts Protective Work Order Holders

Ordering Information

Model Number	Manufacturing Part Number	Product Revision	Package	Operating Temperature
RM008	RM008-23	23		-30 °C to +85 °C

Revision History

Revision	Level	Date	Description
A		October 1999	Initial Release
B		October 2000	Revise: Table 4; Figure 4
C		May 2001	Revise: Converted to standard format; Figure 1 Add: ESD data; Packaging and Handling Information
D		July 26, 2002	Revise: Part Number to RM008-23; ESD data, Package and Handling Add: New Figure 5

References

Application Note: PCB Design and SMT Assembly/Rework, Document Number 101752
JEDEC Standard J-STD-020A.

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